

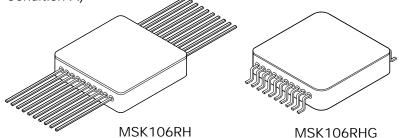
RADIATION HARDENED HIGH POWER 106RH OP-AMP

4707 Dey Road Liverpool, N.Y. 13088

(315) 701-6751

FEATURES:

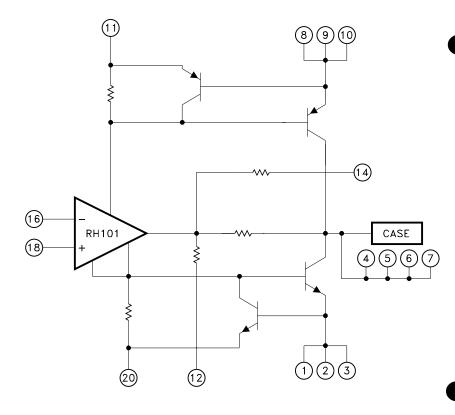
- Manufactured using 4 Logy Space Qualified RH101 Die
- Total Dose Tested to 300K Rad (Method 1019.7 Condition A)
- High Output Current 2 Amps Peak
- Low Power Consumption-Class C Design
- Programmable Current Limit
- Rad Hard Design
- Output Short Circuit Capability
- Rad Hard Replacement for MSK0021FP



DESCRIPTION:

The MSK 106RH is a Radiation Hardened Class C power operational amplifier. This amplifier offers large output currents, making it an excellent choice for motor drive circuits. The amplifier and load can be protected from fault conditions through the use of internal current limit circuitry that can be user programmed with two external resistors. These devices are also compensated with a single external capacitor. The MSK 106RH is packaged in a 20 pin hermetic metal flatpack that is available with straight or gull wing leads.

FOUIVALENT SCHEMATIC



PIN-OUT INFORMATION

1	ISC-	20	-VCC	
2	ISC-	19	NC	
3	ISC-	18	+ VIN	
4	VOUT	17	NC	
5	VOUT	16	-VIN	
6	VOUT	15	NC	
7	VOUT	14	Compensation	
8	ISC+	13	NC	
9	ISC+	12	GND	
10	ISC+	11	+ VCC	
CASE IS ALSO VOUT				

TYPICAL APPLICATIONS

- Servo Amplifier
- Motor Driver
- Audio Amplifier
- Programmable Power Supply

ABSOLUTE MAXIMUM RATINGS

$\pm V$ CC	Supply Voltage ± 22V	Tst	Storage Temperature Range65° to +150°C
			Lead Temperature Range 300° C
VIN	Differential Input Voltage ± 30V		(10 Seconds)
VIN	Common Mode Input Voltage $\cdot \cdot \cdot \cdot \cdot \cdot \cdot \cdot \cdot \pm 15V$	TJ	Junction Temperature
RTH	Thermal Resistance 6.0° C/W	Tc	Case Operating Temperature Range
	Junction to Case (@ 125°C)		Military Versions (K/H/E) -55° C to $+125^{\circ}$ C
			Industrial Versions

ELECTRICAL SPECIFICATIONS

Parameter	Test Conditions	Group A	Military (5)			Industrial ④			
T drameter		Subgroup	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
STATIC									
Supply Voltage Range ②		-	±5	±15	±22	±5	±15	±22	V
Outros and Comment	VIN = OV	1	-	±1.7	±3.5	-	±1.7	±4.0	mA
Quiescent Current		2,3	-	-	± 7.5	-	-	-	mA
Power Consumption 2	VIN = OV	1,2,3	-	75	225	-	75	225	mW
INPUT									
land to Office to Maltage	VIN = OV	1	-	± 0.5	± 3.0	-	±0.5	±5.0	mV
Input Offset Voltage		2, 3	-	±2.0	±5.0	-	-	-	mV
Innut Diag Current	$V_{CM} = OV$	1	-	±100	±500	-	±150	±500	nA
Input Bias Current	Either Input	2, 3	-	± 0.4	± 2.0	-	-	-	μΑ
Input Offset Current	Vcm = 0V	1	-	± 2.0	± 100	-	± 2.0	± 300	nA
·		2,3	-	-	± 300	-	-	-	nA
Input Capacitance ③	F = DC	-	-	3	-	-	3	-	pF
Input Resistance ②	F = DC	-	0.3	1.0	-	0.3	1.0	-	МΩ
Common Mode Rejection Ratio	o $F = 10Hz$ $Vcm = \pm 10V$	4	70	90	-	70	90	-	dB
Common Wode Rejection Ratio		5,6	70	90	-	-	-	-	dB
Power Supply Rejection Ratio		1	80	95	-	80	95	-	dB
		2,3	80	-	-	-	-	-	dB
Input Noise Voltage ③	F = 10Hz to 10KHz	-	-	5	-	-	5	-	μVRMS
OUTPUT									
	$RL = 100\Omega F = 100Hz$	4	± 13.5	± 14	-	± 13.0	± 14	-	V
Output Voltage Swing		5,6	± 13.5	± 14	-	-	-	-	V
	$RL = 10\Omega$ $F = 100Hz$	4	± 11	± 12	-	± 10.5		-	V
Output Short Circuit Current -	$RSC = 0.5\Omega$ $VOUT = MAX$	4	0.8	1.2	1.6	0.7	1.2	1.7	Α
•	$Rsc = 5\Omega$ $Vout = GND$	4	50	150	250	50	150	250	mA
Settling Time ③	0.1% 2V step	-	-	4	-	-	4	-	μS
TRANSFER CHARACTERISTICS									
Slew Rate	Vout = $\pm 10V$ RL = 10Ω	4	1.2	1.4	-	1.0	1.4	-	V/µS
Siew Rate	Post Radiation	4	1.1	-	-	1.1	-	-	V/µS
Open Loop Voltage Gain	$F = 10 Hz RL = 1 K\Omega$	4	100	105	-	100	105	-	dB
Cport 200p Voltage Call		5,6	88	96	-	-	-	-	dB
Transition Times	1V to 2V P Rise and Fall	4	-	0.8	1.0	-	0.8	1.2	μS
Transition fillies	Post Radiation	4	-	1.0	1.2	-	1.0	1.2	μS
Overshoot	1V to 2V P Small Signal		-	5	20	-	5	20	%

NOTES:

- Unless otherwise specified, $\pm Vcc = \pm 15V$, Cc = 3000pF.
- ② Guaranteed by design but not tested.③ Typical parameters are representative of actual device performance but are for reference only.
- 4 Industrial grade and "E" suffix devices shall be tested to subgroups 1 and 4 unless otherwise specified.
- Military grade devices (K/H suffix) shall be 100% tested to subgroups 1, 2, 3 and 4.

 $TA = TC = +25^{\circ}C$ Subgroup 1, 4 $TA = TC = +125^{\circ}C$ Subgroup 2, 5

 $TA = TC = -55^{\circ}C$ Subgroup 3, 6

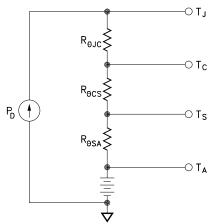
- Reference DSCC SMD TBD for electrical specifications for devices purchased as such.
- Subgroup 5 and 6 testing available upon request.
- ® Continuous operation at or above absolute maximum ratings may adversly effect the device performance and/or life cylcle.
- Pre and post irradiation limits at 25°C, up to 100Krad TID, are identical unless otherwise specified.

APPLICATION NOTES

HEAT SINKING

To select the correct heat sink for your application, refer to the thermal model and governing equation below.

Thermal Model:



Governing Equation:

$$TJ = PD X (R\theta JC + R\theta CS + R\theta SA) + TA$$

Where

TJ = Junction Temperature PD = Total Power Dissipation

ReJC = Junction to Case Thermal Resistance
ReCS = Case to Heat Sink Thermal Resistance
ReSA = Heat Sink to Ambient Thermal Resistance

Tc = Case Temperature
TA = Ambient Temperature
Ts = Sink Temperature

Example:

In our example the amplifier application requires the output to drive a 10 volt peak sine wave across a 10 ohm load for 1 amp of output current. For a worst case analysis we will treat the 1 amp peak output current as a D.C. output current. The power supplies are $\pm\,15$ VDC.

1.) Find Power Dissipation

 $PD = [(quiescent \ current) \ X \ (+ \ Vcc - (Vcc))] \ + \ [(Vs - \ Vo) \ X \ IOUT]$

=
$$(3.5 \text{ mA}) \text{ X } (30\text{V}) + (5\text{V}) \text{ X } (1\text{A})$$

= $0.1\text{W} + 6\text{W}$
= 6.1W

- 2.) For conservative design, set $T_J = +125^{\circ}C$.
- 3.) For this example, worst case $TA = +25^{\circ}C$.
- 4.) ReJC = 6.0° C/W
- 5.) Rearrange governing equation to solve for R θ SA: R θ SA = (TJ TA) / PD (R θ JC) (R θ CS)

= $(125^{\circ}\text{C} - 25^{\circ}\text{C}) / 6.1\text{W} - (6.0^{\circ}\text{C/W}) - (0.15^{\circ}\text{C/W})$ = 10.2°C/W

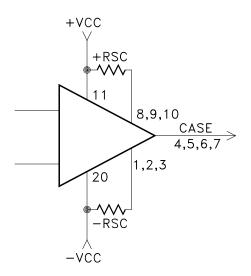
The heat sink in this example must have a thermal resistance of no more than 10.2° C/W to maintain a junction temperature of less than $+125^{\circ}$ C.

CURRENT LIMIT

The MSK 106RH has an on-board current limit scheme designed to limit the output drivers anytime output current exceeds a predetermined limit. The following formula may be used to determine the value of the current limit resistance necessary to establish the desired current limit.

$$RSC = \frac{0.7}{ISC}$$

Current Limit Connection



See "Application Circuits" in this data sheet for additional information on current limit connections.

POWER SUPPLY BYPASSING

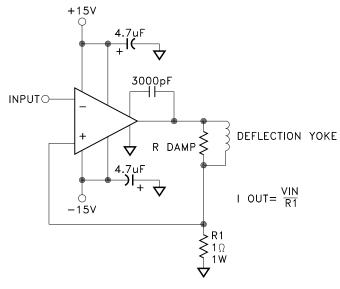
Both the negative and the positive power supplies must be effectively decoupled with a high and low frequency bypass circuit to avoid power supply induced oscillation. An effective decoupling scheme consists of a 0.1 microfarad ceramic capacitor in parallel with a 4.7 microfarad tantalum capacitor from each power supply pin to ground. It is also a good practice with high power op-amps, such as the MSK 106RH, to place a 30-50 microfarad capacitor with a low effective series resistance, in parallel with the other two power supply decoupling capacitors. This capacitor will eliminate any peak output voltage clipping which may occur due to poor power supply load regulation. All power supply decoupling capacitors should be placed as close to the package power supply pins as possible.

TOTAL DOSE RADIATION TEST PERFORMANCE

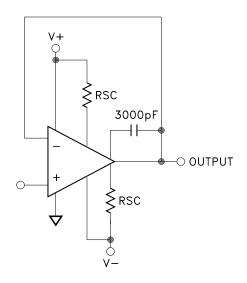
Radiation performance curves for TID testing have been generated for all radiation testing performed by MS Kennedy. These curves show performance trends throughout the TID test process and can be located in the MSK 106RH radiation test report. The complete radiation test report is available in the RAD HARD PRODUCTS section on the MSK website.

http://www.mskennedy.com/store.asp?pid=9951&catid=19680

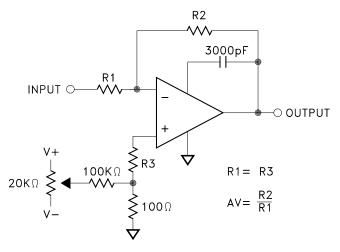
APPLICATION CIRCUITS



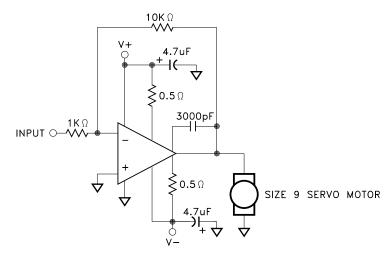
CRT DEFLECTION YOKE DRIVER



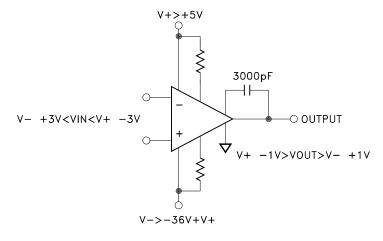
UNITY GAIN CIRCUIT WITH SHORT CIRCUIT LIMITING



OFFSET VOLTAGE NULL CIRCUIT

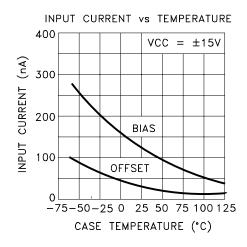


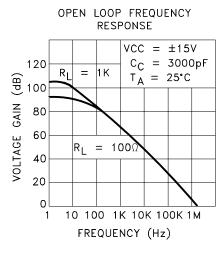
DC SERVO AMPLIFIER

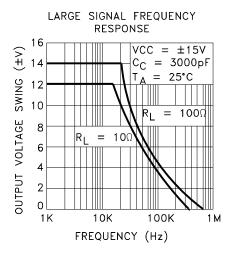


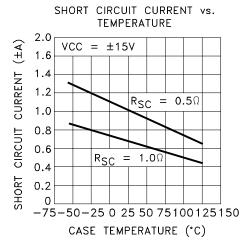
NON SYMMETRICAL SUPPLIES

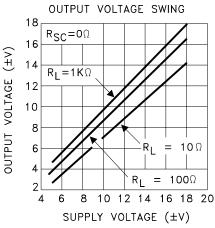
TYPICAL PERFORMANCE CURVES

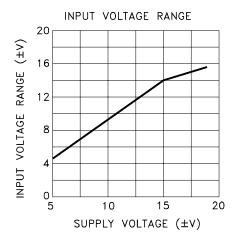


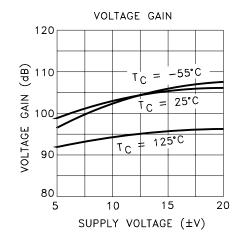


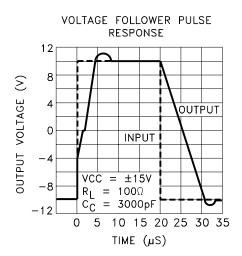




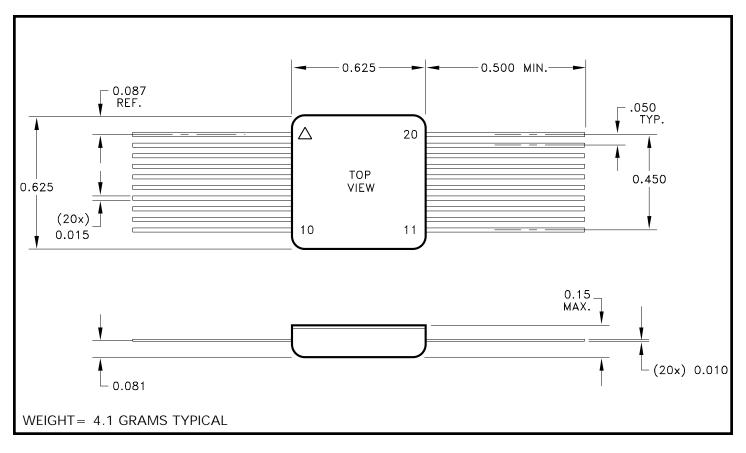








MECHANICAL SPECIFICATIONS CONTINUED

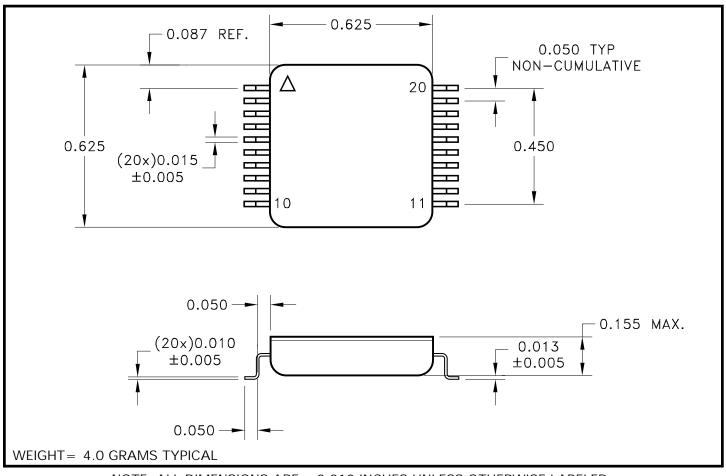


NOTE: ALL DIMENSIONS ARE $\pm\,0.010$ INCHES UNLESS OTHERWISE LABELED. ESD Triangle indicates pin 1.

ORDERING INFORMATION

Part Number	Screening Level
MSK106RH	INDUSTRIAL
MSK106E RH	EXTENDED RELIABILITY
MSK106H RH	MIL-PRF-38534 CLASS H
MSK106K RH	MIL-PRF-38534 CLASS K

MECHANICAL SPECIFICATIONS CONTINUED



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M.S. Kennedy Corp.
4707 Dey Road, Liverpool, New York 13088
Phone (315) 701-6751
Fax (315) 701-6752
www.mskennedy.com

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Please visit our website for the most recent revision of this datasheet.

Contact MSK for MIL-PRF-38534 Class H, Class K and Appendix G (radiation) status.